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MAD		M.K. Weldon, et al Mechanism of Silicon Exfoliation by Hydrogen Implantation and He, Li and Si Co-implantation - IEEE International SOI Conference, October 1997.								
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EXAMINE	ER N	Mark A. Ose	le	DAT	E CONSIDERED)-28-	-04			

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.